

Docket: 0756-958

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT application of )
SHUNPEI YAMAZAKI et al. )

Serial No. 08/183,800 ) Art Unit: 2811

Filed: 01/21/94 ) Examiner: S. Crane

For: SEMICONDUCTOR MATERIAL AND )

METHOD FOR FORMING THE SAME AND )

THIN FILM TRANSISTOR

## CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as First Class Mail in an envelope addressed to: Assistant Commissioner For Patents Washington, D.C. 20231, on

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## **AMENDMENT**

Honorable Assistant Commissioner for Patents

Washington, D.C. 20231

Sir:

In response to the Office Action mailed on September 29, 1998, please

amend the above-identified application as follows:

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